

Probing a Single Quantum Dot & Negative Differential Capacitance

Shidong Wang

Hong Kong University of Science & Technology

Collaborators:

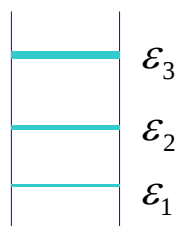
Zhou-Zhou Sun (HKUST) Nelson Cue (HKUST)

X. R. Wang (HKUST) H. Q. Xu (Univ. Lund)

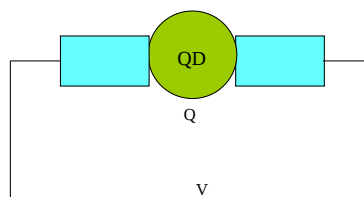
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Two Issues



Probing a single quantum dot



$Q(V) = ?$

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Outline

- **Introduction I**
 - Why nano-structures? Similarity between QD & atoms; Optical and transport measurements
- **Photon-Assistant Tunnelling Measurement**
- **Analysis and Results**
- **Introduction II**
 - Negative differential capacitance
 - Ways of applying bias
- **Model of a QD Connected to Two Leads**
- **Analysis and Results**
 - Existence of negative differential capacitance
- **Summary**

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Why 'nano'?

Trivial reasons

- ❑ Space
- ❑ Time
- ❑ Energy

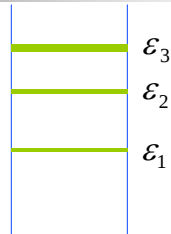
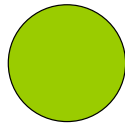
Non-trivial reasons

- ❑ Quantum devices
- ❑ Quantum information processing
 - ❑ Quantum computing
 - ❑ Quantum cryptography
 - ❑ Quantum error correction
 - ❑ Quantum teleportation

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How to Probe a Quantum Dot?

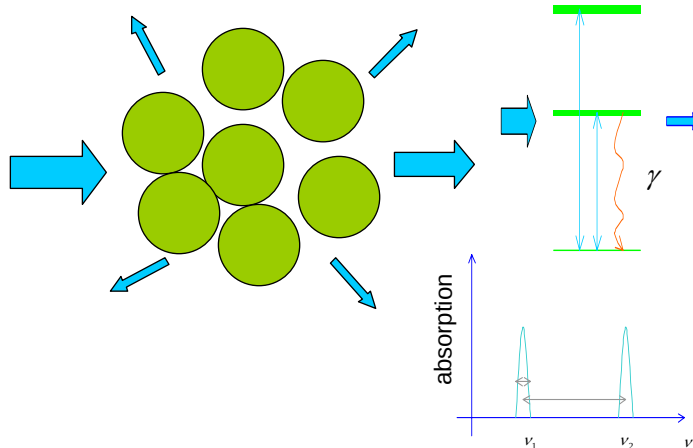


- Similar to atoms
- Difficult to make two identical QD
- Strong e-e interaction

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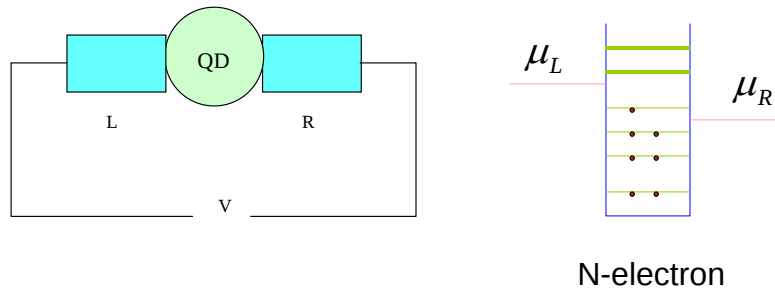
Optical Measurement



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Transport Measurement



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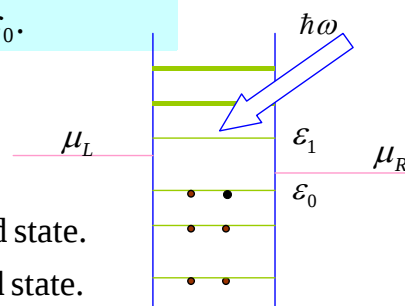
Photon-assistant Tunneling

Assumption : Strong e - e interaction,

$$e^2/C \gg \varepsilon_1 - \varepsilon_0.$$

ε_0 : N - electron ground state.

ε_1 : N - electron excited state.



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Model

$$H = H_0 + H_l + H_t$$

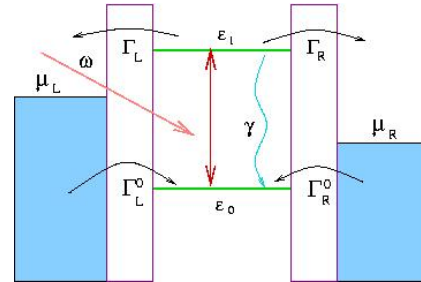
$$H_0 = \varepsilon_0 |0\rangle\langle 0| + \varepsilon_1 |1\rangle\langle 1|$$

$$H_t = \sum_{\alpha,i} (\Gamma_{\alpha,i} c^{\alpha,i} |E\rangle\langle i| + \text{c.c.})$$

$$H_l = -\frac{\hbar}{2} \Omega e^{-i\omega t} |0\rangle\langle 1| + \text{H.c.}$$

α : Label of leads; $|i\rangle$: N - electron states

$|E\rangle$: (N - 1) - electron state; Ω is Rabi frequency



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Approach – Equations of Motion

$$\frac{d\rho}{dt} = -\frac{i}{\hbar} (H_{\text{eff}} \rho - \rho H_{\text{eff}}^+) + \gamma \sigma_- \rho \sigma_+$$

$$\sigma_+ = (\sigma_-)^+ = |i\rangle\langle j|$$

$$H_{\text{eff}} = H - \frac{i\hbar\gamma}{2} \sigma_+ \sigma_-$$

$$\Gamma_0 = \Gamma_L^0 + \Gamma_R^0$$

$$\Gamma = \Gamma_L + \Gamma_R$$

$$\dot{\rho}_E = -\Gamma_0 \rho_E + \Gamma \rho_{11}$$

$$\dot{\rho}_{11} = -(\gamma + \Gamma) \rho_{11} + \text{Im}(\Omega \tilde{\rho}_{10})$$

$$\dot{\tilde{\rho}}_{10} = (i\delta - \frac{\gamma + \Gamma}{2}) \tilde{\rho}_{10} + \frac{i}{2} \Omega (\rho_{00} - \rho_{11})$$

$$\dot{\rho}_{00} = \gamma \rho_{11} + \Gamma_0 \rho_E - \text{Im}(\Omega \tilde{\rho}_{10})$$

$$\rho_{11} + \rho_{00} + \rho_E = 1$$

$$\tilde{\rho}_{10} = \rho_{10} e^{i(\varepsilon_1 - \varepsilon_0)t/\hbar}$$

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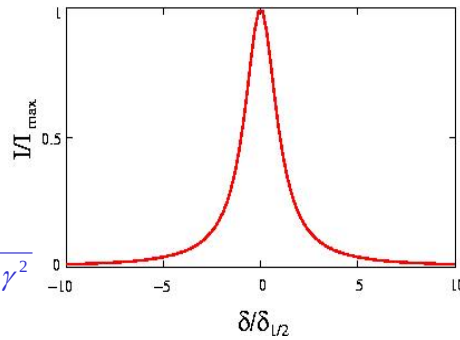


Monochromatic Light

$$I = I_{\max} \frac{\delta_{1/2}^2}{\delta_{1/2}^2 + \delta^2}$$

$$\delta_{1/2} = \frac{1}{2} \sqrt{\Gamma^2 + 2\mathcal{H}\Gamma + \Omega^2\Gamma/\Gamma_0 + 2\Omega^2 + \gamma^2}$$

$$I_{\max} = \frac{(-e)\Omega^2[\Gamma_0(\Gamma_L - \Gamma_R) - \Gamma(\Gamma_L^0 - \Gamma_R^0)]}{\Gamma^2\Gamma_0 + 2\mathcal{H}\Gamma_0 + \Omega^2\Gamma + 2\Omega^2\Gamma_0 + \gamma^2\Gamma_0}$$



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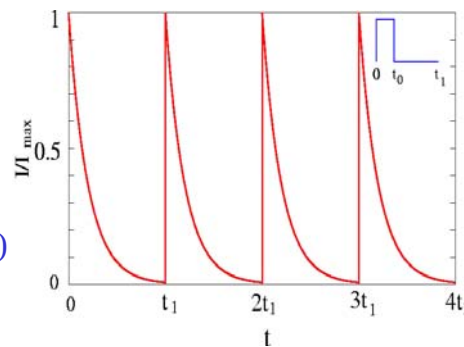
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Pulse

$$I = I_{\max} e^{-(\gamma + \Gamma)t}$$

$$I_{\max} = \frac{(-e) \cos^2\left(\frac{\Omega t_0}{2}\right)}{\Gamma_0 - \gamma - \Gamma} ((\Gamma_0 - \gamma - \Gamma) (\Gamma_L - \Gamma_R) - \Gamma(\Gamma_L^0 - \Gamma_R^0))$$

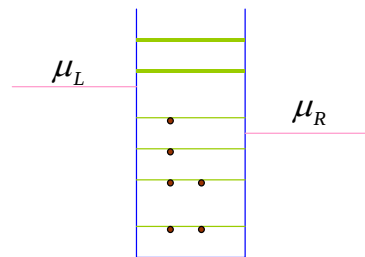


$$t_0 \ll \frac{1}{\gamma}, \frac{1}{\Gamma} \ll t_1$$

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Transport Current



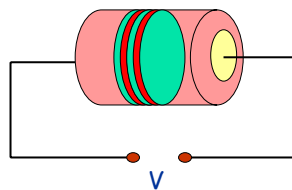
$$I = \frac{2e}{\hbar} \frac{\Gamma_L^0 \Gamma_R^0}{\Gamma_L^0 + \Gamma_R^0}$$

N-electron ground state

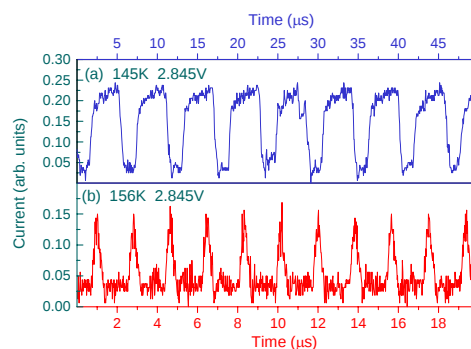
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Why Negative Differential Capacitance?



Like negative differential resistance, negative differential capacitance can also cause the instability.

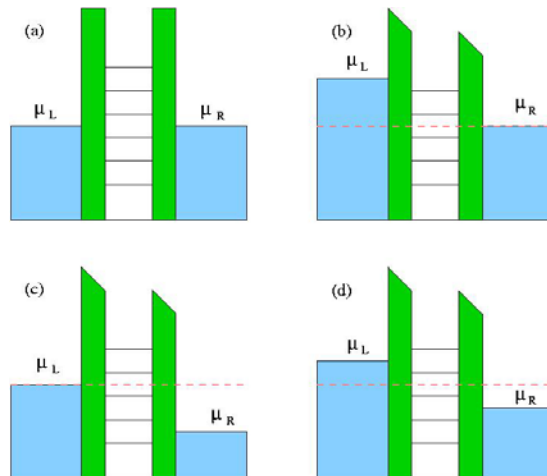


self-sustained current oscillation in superlattice caused by NDR

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Is Negative Differential Capacitance Possible?



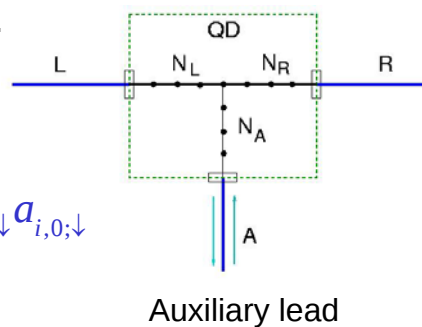
Three ways
of applying
a bias

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Model

$$H = H_0 + \sum_{i=-N_L}^{N_R} U a_{i,0;\uparrow}^+ a_{i,0;\uparrow} a_{i,0;\downarrow}^+ a_{i,0;\downarrow} + \sum_{m=1}^{N_A} U a_{0,m;\uparrow}^+ a_{0,m;\uparrow} a_{0,m;\downarrow}^+ a_{0,m;\downarrow}$$



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Hartree-Fock Approximation

$$H_0^{eff} = \sum_{i,m,\sigma} \varepsilon_{i,m;\sigma}^{eff} a_{i,m;\sigma}^+ a_{i,m;\sigma} + \sum_{\langle i,j \rangle \langle m,n \rangle, \sigma} t_{i,j,m,n} a_{i,m;\sigma}^+ a_{j,n;\sigma} + \text{c.c.},$$

$$\varepsilon_{i,m;\sigma}^{eff} = \varepsilon_{i,m;\sigma} + U \langle n_{i,m;\bar{\sigma}} \rangle \quad \sigma = -\bar{\sigma},$$

$$\langle n_{i,m;\sigma} \rangle = -\frac{1}{\pi} \int_{-\infty}^{\mu_A} \text{Im} \langle i, m; \sigma | G^{eff}(E) | i, m; \sigma \rangle dE$$

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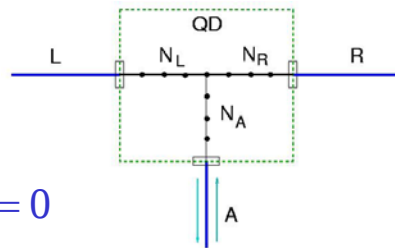
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Calculation of Current

$$I_A = -\frac{2e}{h} \int_{\mu_A}^{\mu_L} T_{A \leftarrow L}(E) dE + \frac{2e}{h} \int_{\mu_R}^{\mu_A} T_{R \leftarrow A}(E) dE = 0$$

$$I_{R \leftarrow L} = -\frac{2e}{h} \left(\int_{\mu_R}^{\mu_L} T_{R \leftarrow L}(E) dE + \int_{\mu_R}^{\mu_A} T_{R \leftarrow A}(E) dE \right)$$

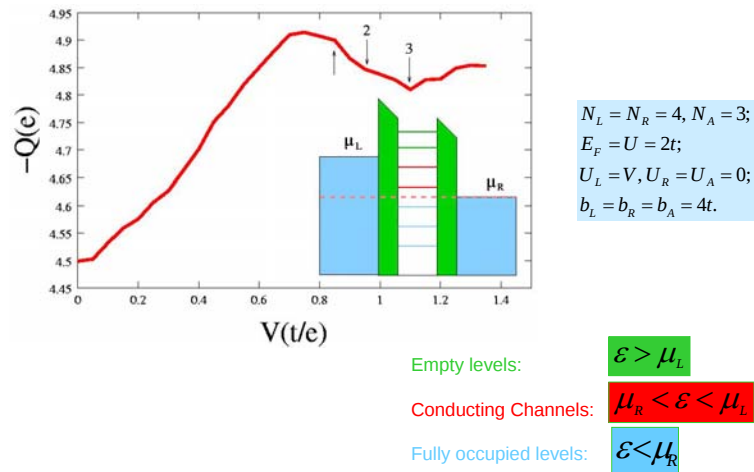
$$Q = \sum_{\sigma, i=-N_L}^{N_R} e \langle n_{i,0;\sigma} \rangle + \sum_{\sigma; m=1}^{N_A} e \langle n_{0,m;\sigma} \rangle$$



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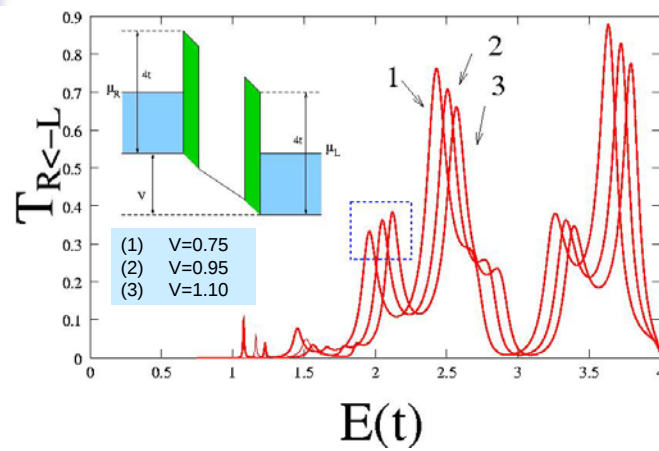
Numerical Evidence of NDC



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Transmission Coefficients



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Why Does It Happen?

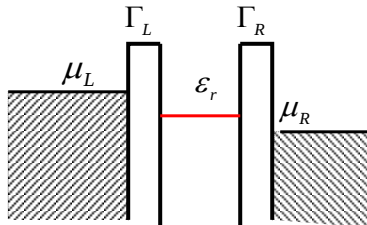
$T = 0$

$$I_{L \rightarrow D} = \frac{2e}{\hbar} \Gamma_L f_L (1 - f_r)$$

$$I_{D \rightarrow R} = \frac{2e}{\hbar} \Gamma_R f_r (1 - f_R)$$

$$I_{L \rightarrow D} = I_{D \rightarrow R}$$

$$Q = ef_r$$



$$Q_r = \frac{e\Gamma_L}{\Gamma_L + \Gamma_R} = \frac{e}{1 + \Gamma_R/\Gamma_L}$$

$dQ_r/dV < 0$ if Γ_R/Γ_L increases with bias V

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Summary

- Combining the microwave pumping and electron tunneling measurement, one can obtain the spontaneous emission rate of a single electron level of a quantum dot.
- Present numerical evidences of an NDC in a QD.
- NDC is caused by the bias dependence of the electron tunneling rates in a weakly coupled QD.

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